EFC6605R

ON Semiconductor®

ON Semiconduct

N-Channel Power MOSFET 20V, 10A, 13.3mΩ, Dual EFCP

Features

- 2.5V drive
- Protection diode in
- Halogen free compliance

- Common-drain type
- 2KV ESD HBM

Applications

• Lithium-ion battery charging and discharging switch

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Value	Unit
Source to Source Voltage	V _{SSS}		20	V
Gate to Source Voltage	V _{GSS}		±10	٧
Source Current (DC)	IS		10	Α
Source Current (Pulse)	I _{SP}	PW≤10μs, duty cycle≤1%	60	Α
Total Dissipation	PT	When mounted on ceramic substrate (5000mm ² ×0.8mm)	1.6	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		- 55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Ambient	$R_{\theta JA}$	78.1	°C /W
When mounted on ceramic substrate (5000mm ² ×0.8mm)			

Electrical Characteristics at Ta = 25°C

Parameter	Cumbal	Conditions		Value			Unit
Parameter	Symbol			min	typ	max	Unit
Source to Source Breakdown Voltage	V(BR)SSS	I _S =1mA, V _{GS} =0V	Test Circuit 1	20			V
Zero-Gate Voltage Source Current	ISSS	V _{SS} =20V, V _{GS} =0V	Test Circuit 1			1	μА
Gate to Source Leakage Current	IGSS	VGS=±8V, VSS=0V	Test Circuit 2			±1.0	μА
Gate Threshold Voltage	V _{GS} (th)	V _{SS} 10V, I _S =1mA	Test Circuit 3	0.5		1.3	V
Forward Transconductance	9FS	V _{SS} =10V, I _S =3A	Test Circuit 4		11.4		S
	RSS(on)1	IS=3A, VGS=4.5V	Test Circuit 5	8.8	11.1	13.3	mΩ
	RSS(on)2	IS=3A, VGS=4.0V	Test Circuit 5	9.1	11.4	13.7	mΩ
Static Source to Source On-State Resistance	RSS(on)3	IS=3A, VGS=3.8V	Test Circuit 5	9.3	11.6	13.9	mΩ
Nesisiance	RSS(on)4	IS=3A, VGS=3.1V	Test Circuit 5	10.0	12.5	15.6	mΩ
	RSS(on)5	IS=3A, VGS=2.5V	Test Circuit 5	11.1	13.9	17.4	mΩ

Continued on next page.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

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Continued from preceding page.

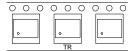
Parameter	0	Value	Value		11.3	
	Symbol	Conditions	min typ max		Unit	
Turn-ON Delay Time	t _d (on)			154		ns
Rise Time	t _r	V _{SS} =10V, V _{GS} =4.5V, I _S =3A Test Circuit 6		678		ns
Turn-OFF Delay Time	t _d (off)			44400		ns
Fall Time	tf			60800		ns
Total Gate Charge	Qg	V _{SS} =10V, V _{GS} =4.5V, I _S =10A Test Circuit 7		19.8		nC
Forward Source to Source Voltage	V _F (S-S)	I _S =3A, V _{GS} =0V Test Circuit 8		0.75	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

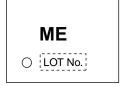
Ordering & Package Information

Device	Package	Shipping	note
EFC6605R-TR	EFCP	5,000 pcs. / reel	Pb-Free and Halogen Free

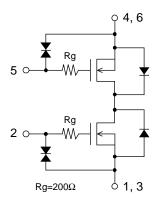
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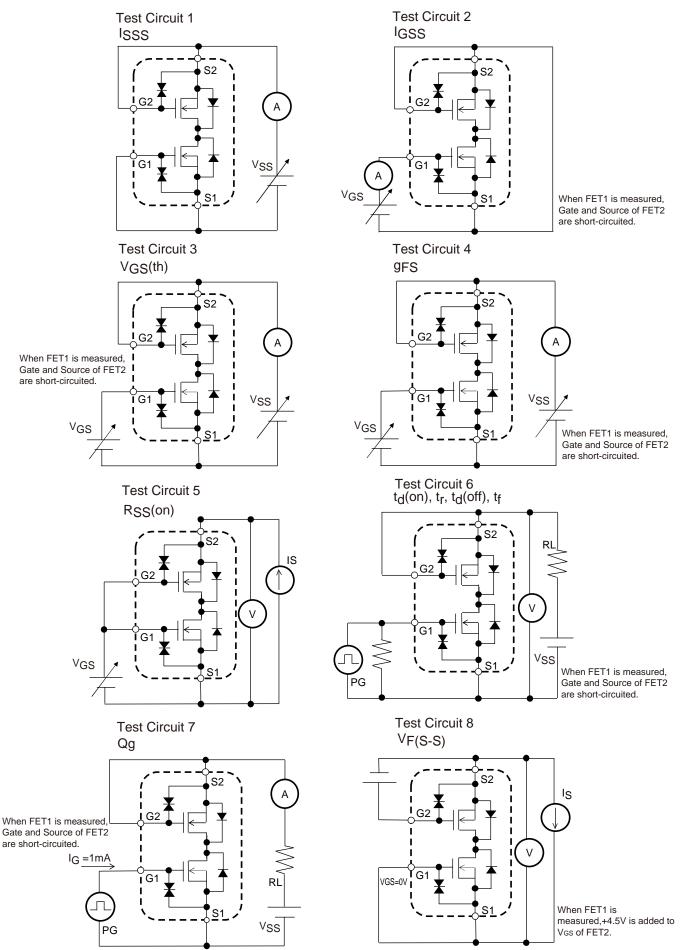
Marking



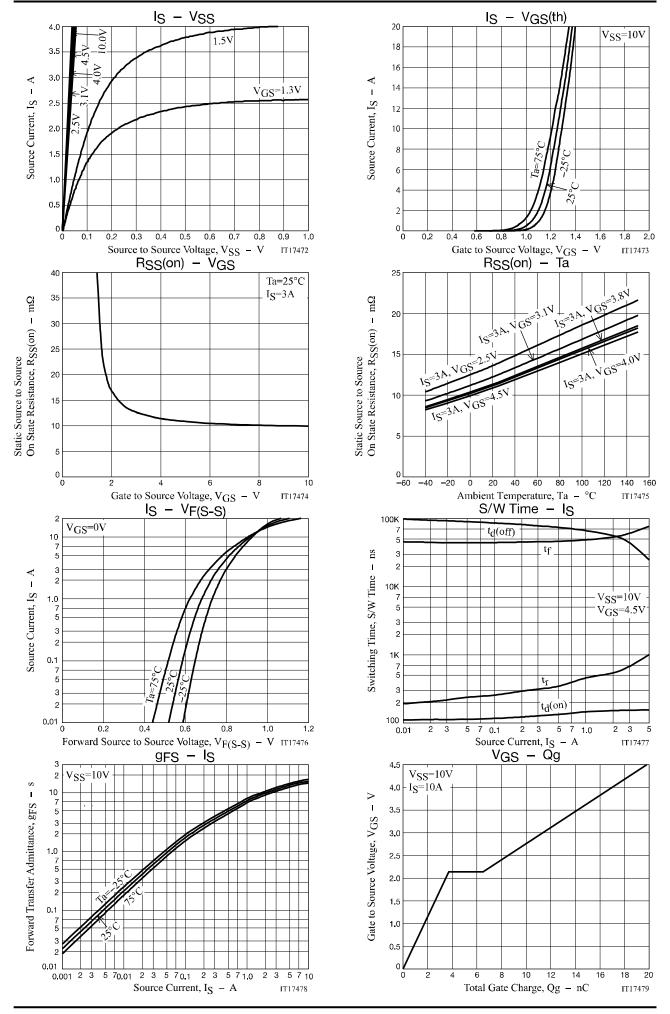
Electrical Connection



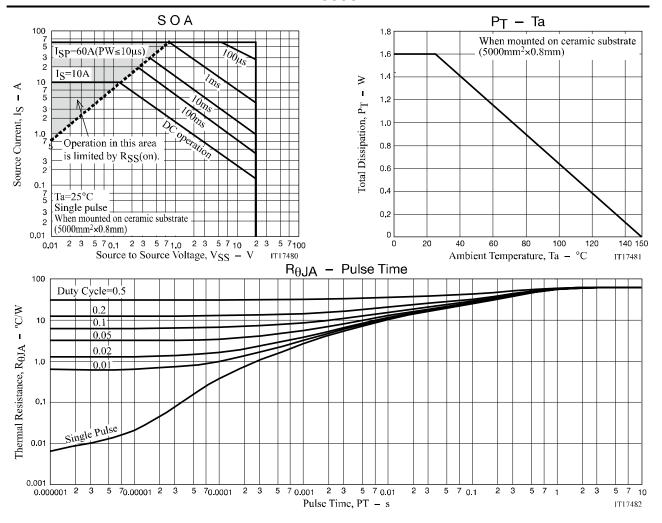
Test circuits are example of measuring FET1 side



When FET2 is measured, the position of FET1 and FET2 is switched.



EFC6605R



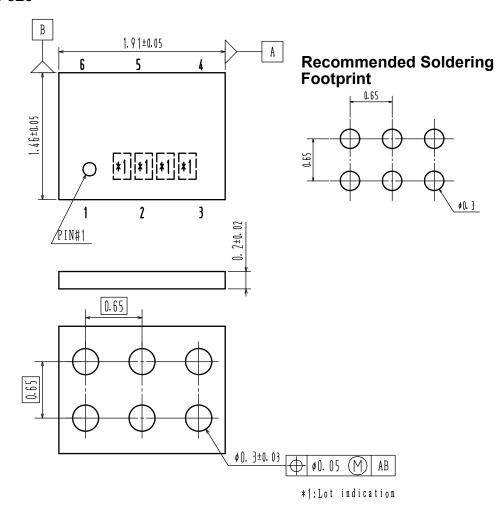
Package Dimensions

EFC6605R-TR

EFCP1915-6CE-020

unit: mm

- 1: Source1
- 2: Gate1
- 3: Source1
- 4: Source2
- 5: Gate2
- 6: Source2



Note on usage : Since the EFC6605R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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